

Low Voltage Hex Inverter / Buffer with Open Drain Outputs

74LCX06

General Description

The LCX06 contains six inverters/buffers. The inputs tolerate voltages up to 5.5 V allowing the interface of 5 V systems to 3 V systems.

The outputs of the LCX06 are open drain and can be connected to other open drain outputs to implement

The 74LCX06 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5 V Tolerant Inputs
- 1.65 V 5.5 V V_{CC} Specifications Provided
- 3.7 ns t_{PD} Max. $(V_{CC} = 3.3 \text{ V})$
- 10 μA I_{CC} Max.
- Power Down High Impedance Inputs and Outputs
- ± 24 mA Output Drive (V_{CC} = 3.0 V)
- Implements Proprietary Noise/EMI Reduction Circuitry
- Latch-up Performance Exceeds 100 mA
- ESD Performance:
 - ♦ Human Body Model > 2000 V
- This Device is Pb-Free, Halide Free and RoHS Compliant

Logic Symbol

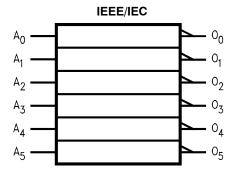


Figure 1. Logic Symbol

PIN DESCRIPTION

Pin Name	Description
A _n , B _n	Inputs
\overline{O}_n	Outputs



MARKING DIAGRAMS

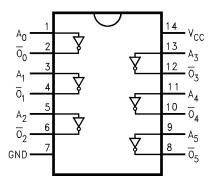


XXXXXX = Specific Device Code A = Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ABSOLUTE MAXIMUM RATINGS

Symbol	Pa	arameter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
VI	DC Input Voltage (Note 1)		-0.5 to +6.5	V
Vo	DC Output Voltage (Note 1)	Active-Mode (High or Low State)	-0.5 to V _{CC} + 0.5	V
		Tri-State Mode	-0.5 to +6.5	V
		Power-Down Mode (V _{CC} = 0 V)	-0.5 to +6.5	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
lok	DC Output Diode Current	e Current V _O < GND		mA
Io	DC Output Source / Sink Current	±50	mA	
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case fo	r 10 secs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 1)		150	°C/W
P _D	Power Dissipation in Still Air at 125 °C		833	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. IO absolute maximum rating must be observed.
- Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
V _{CC}	Supply Voltage	Operating	1.65	3.3	5.5	V
		Data Retention Only	1.5	3.3	5.5	
VI	Digital Input Voltage		0	-	5.5	V
Vo	Output Voltage	Active Mode (High or Low State)	0	-	V _{CC}	V
		Tri-State Mode	0	-	5.5	
		Power Down Mode (V _{CC} = 0 V)	0	-	5.5	
T _A	Operating Free-Air Temperature		-40	-	+125	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 1.65 V to 1.95 V	0	-	20	nS/V
		V _{CC} = 2.3 V to 2.7 V	0	-	20	
		V _I from 0.8 V to 2.0 V, V _{CC} = 3.0 V	0	-	10	
		V _{CC} = 4.5 V to 5.5 V	0	-	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} (V)	$T_A = -40^{\circ}$	C to +85°C	T _A = -40°C	to +125°C	Unit
				Min	Max	Min	Max	
V _{IH}	HIGH Level Input Voltage		1.65 – 1.95	0.65 x V _{CC}	-	0.65 x V _{CC}	-	V
			2.3 – 2.7	1.7	_	1.7	-	
			3.0 – 3.6	2.0	_	2.0	-	
			4.5 – 5.5	0.70 x V _{CC}	_	0.70 x V _{CC}	-	
V _{IL}	LOW Level Input Voltage		1.65 – 1.95	-	0.35 x V _{CC}	-	0.35 x V _{CC}	V
			2.3 – 2.7	-	0.7	-	0.7	
			3.0 – 3.6	-	0.8	-	0.8	
			4.5 – 5.5	-	0.30 x V _{CC}	_	0.30 x V _{CC}	
V _{OL}	Low-Level Output	$V_I = V_{IH}$ or V_{IL}						V
	Voltage	I _{OL} = 100 μA	1.65 to 5.5	_	0.1	_	0.1	
		$I_{OL} = 4 \text{ mA}$	1.65	_	0.24	_	0.24	
		$I_{OL} = 8 \text{ mA}$	2.3	_	0.3	_	0.3	
		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	_	0.4	
		I _{OL} = 16 mA	3.0	_	0.4	_	0.4	
		$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	_	0.55	
		$I_{OL} = 32 \text{ mA}$	4.5	_	0.6	_	0.6	
l _{OZ}	3-State Output Leakage Current	$V_I = V_{IH} \text{ or } V_{IL},$ $V_O = 0 \text{ to } 5.5 \text{ V}$	3.6	-	±5.0	-	±5.0	μΑ
I _I	Input Leakage Current	V _I = 0 to 5.5 V	1.65 – 5.5	-	±5.0	_	±5.0	μΑ
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or V _O = 5.5 V	0	-	10	-	10	μΑ
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	1.65 – 5.5	-	10	-	10	μΑ
ΔI_{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} - 0.6 V	2.3 – 3.6	_	500	_	500	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

				T _A = -40 °C	to +85 °C	T _A = -40 °C	to +125 °C	
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Max	Min	Max	Unit
t _{PLZ} , t _{PZL}	Propagation Delay, See Figures 2 and Figure 4		1.65 to 1.95	-	6.5	-	6.5	ns
		and Figure 4	2.3 to 2.7	-	3.5	-	3.5	
			2.7	-	4.1	-	4.1	
			3.0 to 3.6	-	3.7	-	3.7	
			4.5 to 5.5	-	3.2	-	3.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

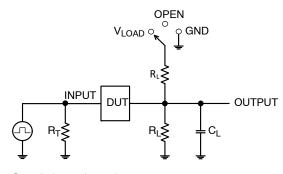
DYNAMIC SWITCHING CHARACTERISTICS

				T _A = 25°C	
Symbol	Parameter	V _{CC} (V)	Condition	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	0.9	٧
		2.5	$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	0.7	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	-0.8	V
		2.5	C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V	-0.6	

CAPACITANCE

Symbol	Parameter	Condition	Тур	Unit
C _{IN}	Input Capacitance	V _{CC} = Open, V _I = 0 V or V _{CC}	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CC}$	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CC}, f = 10 \text{ MHz}$	25	pF

TEST CIRCUITS



 Test
 Switch Position

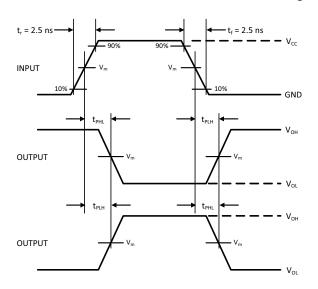
 t_{PLH} / t_{PHL}
 Open

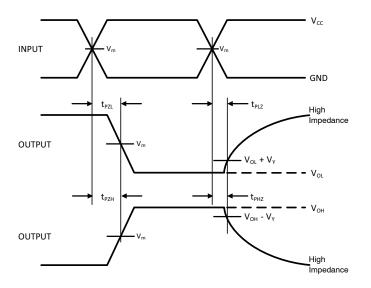
 t_{PLZ} / t_{PZL}
 V_{LOAD}

 t_{PHZ} / t_{PZH}
 GND

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

Figure 2. Test Circuit





V _{CC} , V	R_L,Ω	C _L , pF	V_{LOAD}	V _m , V	V _Y , V
1.65 to 1.95	500	30	2 x V _{CC}	V _{CC} /2	0.15
2.3 to 2.7	500	30	2 x V _{CC}	V _{CC} /2	0.15
2.7	500	50	6 V	1.5	0.3
3.0 to 3.6	500	50	6 V	1.5	0.3
4.5 to 5.5	500	50	2 x V _{CC}	V _{CC} /2	0.3

Figure 3. Switching Waveforms

74LCX06

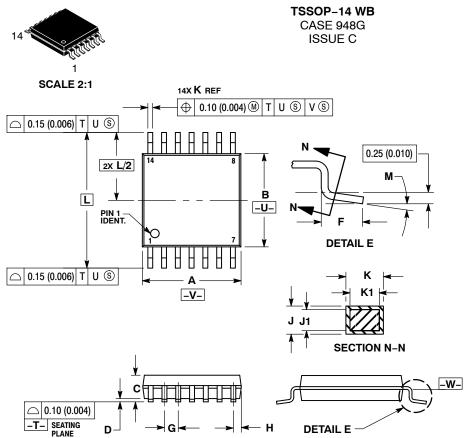
ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74LCX06MTCX	LCX 06	TSSOP-14 (Pb-Free, Halide Free)	2500 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DATE 17 FEB 2016





- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40		0.252	BSC
М	0 °	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*



= Assembly Location

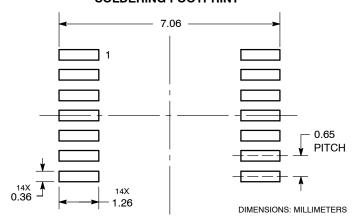
= Wafer Lot L = Year = Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	TSSOP-14 WB		PAGE 1 OF 1	

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